

## isc N-Channel MOSFET Transistor

2SK2077

## DESCRIPTION

- Drain Current  $I_D = 7A @ T_C = 25^\circ C$
- Drain Source Voltage-  
:  $V_{DSS} = 800V(\text{Min})$
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

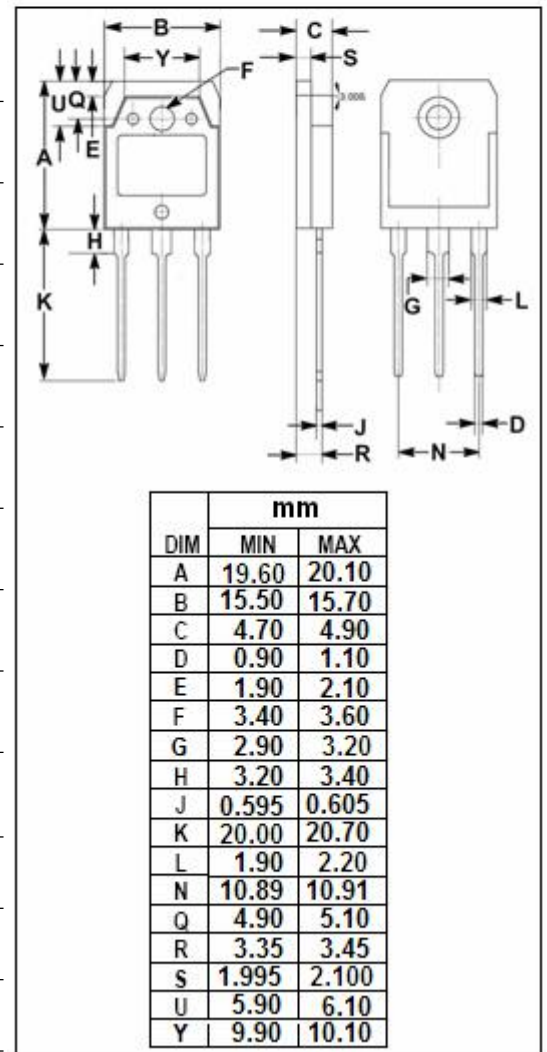
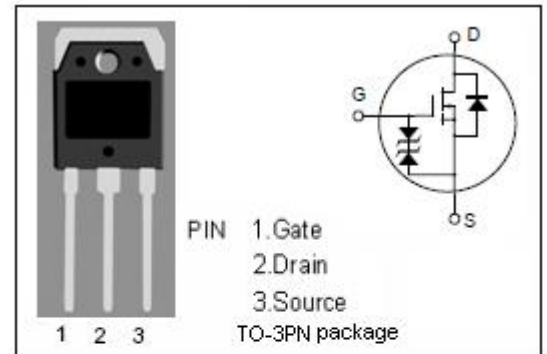
- Switching regulators
- General purpose power amplifier

ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ C$ )

| SYMBOL        | PARAMETER                                    | VALUE    | UNIT       |
|---------------|----------------------------------------------|----------|------------|
| $V_{DSS}$     | Drain-Source Voltage ( $V_{GS}=0$ )          | 800      | V          |
| $V_{GS}$      | Gate-Source Voltage                          | $\pm 30$ | V          |
| $I_D$         | Drain Current-continuous@ $T_C = 25^\circ C$ | 7        | A          |
| $I_{D(puls)}$ | Pulsed Drain Current                         | 21       | A          |
| $P_{tot}$     | Total Dissipation@ $T_C = 25^\circ C$        | 150      | W          |
| $T_j$         | Max. Operating Junction Temperature          | 150      | $^\circ C$ |
| $T_{stg}$     | Storage Temperature Range                    | -55~150  | $^\circ C$ |

## • THERMAL CHARACTERISTICS

| SYMBOL       | PARAMETER                               | MAX   | UNIT         |
|--------------|-----------------------------------------|-------|--------------|
| $R_{th j-c}$ | Thermal Resistance, Junction to Case    | 0.833 | $^\circ C/W$ |
| $R_{th j-a}$ | Thermal Resistance, Junction to Ambient | 50    | $^\circ C/W$ |



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• ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25°C)

| SYMBOL               | PARAMETER                       | CONDITIONS                                                                                        | MIN | TYPE | MAX  | UNIT |
|----------------------|---------------------------------|---------------------------------------------------------------------------------------------------|-----|------|------|------|
| V <sub>(BR)DSS</sub> | Drain-Source Breakdown Voltage  | V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA                                                        | 800 |      |      | V    |
| V <sub>GS(th)</sub>  | Gate Threshold Voltage          | V <sub>DS</sub> =10V; I <sub>D</sub> =1mA                                                         | 1.5 |      | 3.5  | V    |
| R <sub>DS(on)</sub>  | Drain-Source On-Resistance      | V <sub>GS</sub> = 10V; I <sub>D</sub> = 3.5A                                                      |     | 1.4  | 1.7  | Ω    |
| I <sub>GSS</sub>     | Gate-Body Leakage Current       | V <sub>GS</sub> = ±30V; V <sub>DS</sub> = 0                                                       |     |      | ±100 | nA   |
| I <sub>DSS</sub>     | Zero Gate Voltage Drain Current | V <sub>DS</sub> = 640V; V <sub>GS</sub> = 0                                                       |     |      | 300  | μA   |
| C <sub>iss</sub>     | Input Capacitance               | V <sub>DS</sub> =25V;<br>V <sub>GS</sub> =0V;<br>f <sub>r</sub> =1MHz                             |     | 810  |      | pF   |
| C <sub>rss</sub>     | Reverse Transfer Capacitance    |                                                                                                   |     | 100  |      |      |
| C <sub>oss</sub>     | Output Capacitance              |                                                                                                   |     | 160  |      |      |
| t <sub>r</sub>       | Rise Time                       | V <sub>GS</sub> =10V;<br>I <sub>D</sub> =3.5A;<br>V <sub>DD</sub> =400V;<br>R <sub>L</sub> =110 Ω |     | 170  |      | ns   |
| t <sub>on</sub>      | Turn-on Time                    |                                                                                                   |     | 190  |      |      |
| t <sub>f</sub>       | Fall Time                       |                                                                                                   |     | 160  |      |      |
| t <sub>off</sub>     | Turn-off Time                   |                                                                                                   |     | 570  |      |      |

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